

TOSHIBA Photocoupler GaAs Ired+Photo-Triac

# TLP763J

Office Machine Household Use Equipment Triac Driver Solid State Relay

The TOSHIBA TLP763J consists of a GaAs infrared LED optically coupled to a zero voltage crossing turn-on photo-triac in a 6 lead plastic DIP.

- Peak off-state voltage: 600 V (min.)
- Trigger LED current: 10 mA (max.)
- On-state current: 100 mA (max.)
- Isolation voltage: 4000Vrms (min.)
- UL recognized: UL1577, file No. E67349
  - BSI approved: BS EN60065: 1994, Certificate No. 7831 BS EN60065: 1992,
    - Certificate No. 7832
- SEMKO approved: SS–EN60065 (EN60065, 1993) SS–EN60950 (EN60950, 1992) SS–EN60335 (EN60335, 1988)
  - Certificate No. 9522145
- Option (D4) type

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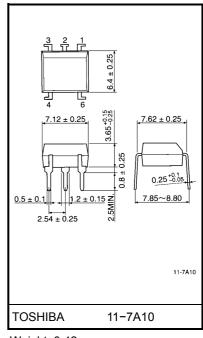
VDE approved: DIN VDE0884, 06.92

Certificate No. 91803

Maximum operating insulation voltage: 890 VPK Highest permissible over voltage: 6000 VPK

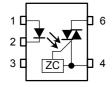
### (Note) When a VDE0884 approved type is needed, please designate the "option (D4)"

		7.62mm pich	10.16mm pich
		TLP763J type	TLP763JF type
•	Creepage distance	: 7.0mm (min.)	8.0mm (min.)
	Clearance	: 7.0mm (min.)	8.0mm (min.)
	Internal creepage path	: 4.0mm (min.)	4.0mm (min.)
	Insulation thickness	: 0.5mm (min.)	0.5mm (min.)





## Pin Configuration (top view)



<sup>1 :</sup> Anode 2 : Cathode 3 : Nc 4 : Triac 1

Unit in mm

<sup>6 :</sup> Triac 2

### Maximum Ratings (Ta = 25°C)

Characteristic			Symbol	Rating	Unit
	Forward current		١ <sub>F</sub>	50	mA
LED	Forward current derating (Ta ≥ 53°C)		ΔI <sub>F</sub> /°C	-0.7	mA/°C
	Peak forward current (100 µs pulse, 100 pps)		I <sub>FP</sub>	1	Α
	Reverse voltage		V <sub>R</sub>	5	V
	Junction temperature		Tj	125	°C
	Off-state output terminal voltage	V <sub>DRM</sub>	600	V	
	On-state RMS current	Ta = 25°C	I <sub>T(RMS)</sub>	100	mA
L		Ta = 70°C		50	MA
Detector	On-state current derating (Ta ≥ 25	ΔI <sub>T</sub> /°C	-1.1	mA/°C	
Det	Peak on-state current (100µs puls	I <sub>TP</sub>	2	Α	
	Peak nonrepetitive surge current (PW = 10 ms, DC = 10%)		I <sub>TSM</sub>	1.2	А
	Junction temperature	Tj	115	°C	
Storage temperature range			T <sub>stg</sub>	-55~125	°C
Operating temperature range			T <sub>opr</sub>	-40~100	°C
Lead soldering temperature (10s)			T <sub>sol</sub>	260	°C
Isolation voltage (AC, 1 min., R.H.≤ 60%)			BVS	4000	Vrms

### **Recommended Operating Conditions**

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V <sub>AC</sub>			240	Vac
Forward current	١ <sub>F</sub>	15	20	25	mA
Peak on-state current	I <sub>TP</sub>	_	_	1	А
Operating temperature	T <sub>opr</sub>	-25	_	85	°C

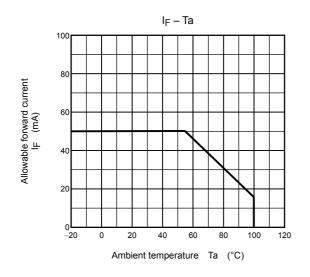
### Individual Electrical Characteristics (Ta = 25°C)

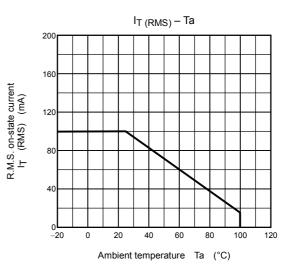
	Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
ĒD	Forward voltage	VF	I <sub>F</sub> = 10 mA	1.0	1.15	1.3	V
	Reverse current	I <sub>R</sub>	V <sub>R</sub> = 5 V	_	_	10	μA
	Capacitance	CT	V = 0, f = 1 MHz	-	30	_	pF
	Peak off-state current	I <sub>DRM</sub>	V <sub>DRM</sub> = 600 V	_	10	1000	nA
	Peak on-state voltage	V <sub>TM</sub>	I <sub>TM</sub> = 100 mA		1.7	3.0	V
ctor	Holding current	Iн	_	-	0.6	_	mA
Detector	Critical rate of rise of off-state voltage	dv / dt	Vin = 240 V, Ta = 85°C	_	500	_	V/µs
	Critical rate of rise of commutating voltage	dv / dt (c)	I <sub>T</sub> = 15 mA Vin = 60Vrms	_	0.2	_	V/µs

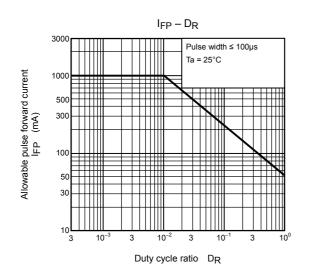
### Coupled Electrical Characteristics (Ta = 25°C)

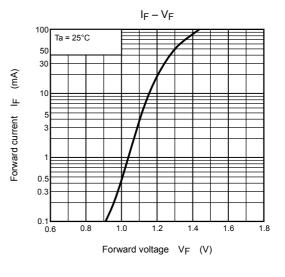
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Trigger LED current	I <sub>FT</sub>	V <sub>T</sub> = 6 V	_	—	10	mA
Inhibit voltage	V <sub>IH</sub>	I <sub>F</sub> = rated I <sub>FT</sub>	—	_	50	V
Leakage in inhibited state	IIН	I <sub>F</sub> = rated I <sub>FT</sub> V <sub>T</sub> = rated V <sub>DRM</sub>	_	200	600	μA
Capacitance (input to output)	CS	V <sub>S</sub> = 0, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R <sub>S</sub>	V <sub>S</sub> = 500 V	1×10 <sup>12</sup>	10 <sup>14</sup>	_	Ω
	BVS	AC, 1 minute	4000	_	_	Vrms
Isolation voltage		AC, 1 second, in oil	_	10000	_	
		DC, 1 minute, in oil	—	10000	_	V <sub>dc</sub>

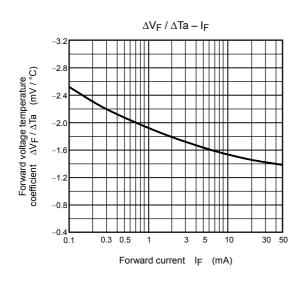
### TOSHIBA

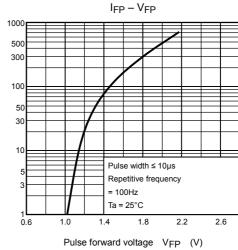












(mA)

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Pulse forward current

#### **RESTRICTIONS ON PRODUCT USE**

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